Kingbright

AM4457P3C-F-R

Phototransistor



DESCRIPTION

· Made with NPN silicon phototransistor chips

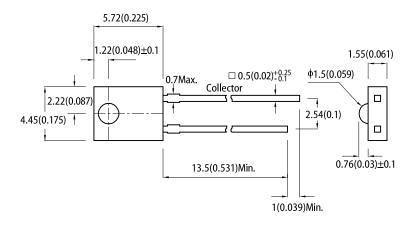
FEATURES

- · Mechanically and spectrally matched to infrared emitting LED lamp
- Package matched with IR emitter AM4457F3C
- Halogen-free
- · Water clear lens
- RoHS compliant

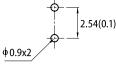
APPLICATIONS

- Infrared applied systems
- Optoelectronic switches
- · Photodetector control circuits
- Sensor technology

PACKAGE DIMENSIONS



Recommended PCB Layout



Notes

Notes: 1. All dimensions are in millimeters (inches). 2. Tolerance is ±0.25(0.01") unless otherwise noted. 3. Lead spacing is measured where the leads emerge from the package. 4. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Max.Ratings	Units
Collector-to-Emitter Voltage	30	V
Emitter-to-Collector Voltage	5	V
Power Dissipation at (or below) 25°C Free Air Temperature	100	mW
Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +85	°C
Lead Soldering Temperature(>5mm for 5sec)	260	°C

Note: 1. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

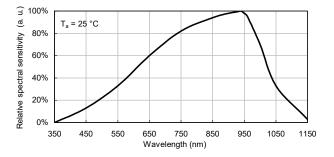
Kingbright

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

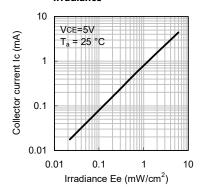
Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Collector-to-Emitter Breakdown Voltage	V _{BR CEO}	30	-	-	V	I _C = 100μA E _e = 0mW/cm ²
Emitter-to-Collector Breakdown Voltage	V _{BR ECO}	5	-	-	V	$I_E = 100 \mu A$ $E_e = 0 m W/cm^2$
Collector-to-Emitter Saturation Voltage	V _{CE (SAT)}	-	-	0.8	V	$I_{C} = 2mA$ $E_{e} = 20mW/cm^{2}$
Collector Dark Current	I _{CEO}	-	-	100	nA	V_{CE} = 10V E _e = 0mW/cm ²
Rise Time(10% to 90%)	tr	-	15	-	μS	V _{CE} = 5V I _C = 1mA R _L = 1000Ω
Fall Time(90% to 10%)	t _f	-	15	-	μS	
On State Collector Current	I _(ON)	0.35	0.8	-	mA	$V_{CE} = 5V$ $E_e = 1mW/cm^2$ $\lambda = 940nm$
Range of Spectral Bandwidth	λ _{0.1}	420	-	1120	nm	-
Wavelength of Peak Sensitivity	λ_{p}	-	940	-	nm	-

TECHNICAL DATA

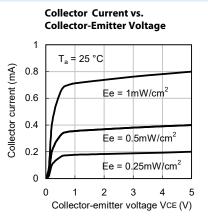
RELATIVE SPECTRAL SENSITIVITY vs. WAVELENGTH



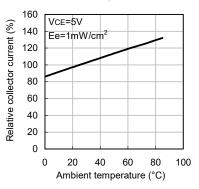
Collector Current vs. Irradiance



PHOTOTRANSISTOR



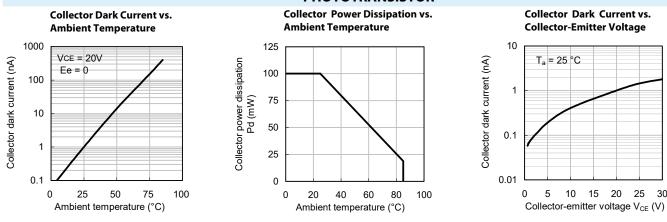
Relative Collector Current vs. Ambient Temperature



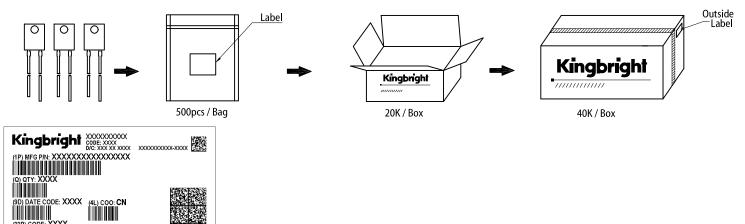
Kingbright

TECHNICAL DATA





PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications. 2
- 3 When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening
- 4 liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright.
- 5
- 6 All design applications should refer to Kingbright application notes available at https://www.K Notes

1 RoHS Compliant

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Kingbright:

AM4457P3C-F-R